



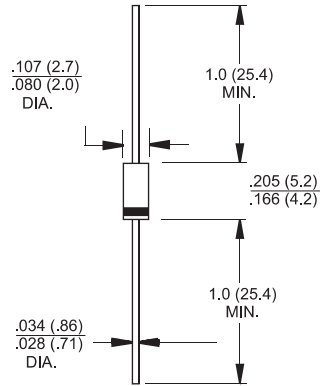
### Features

- ✦ Glass passivated chip junction.
- ✦ High efficiency, Low VF
- ✦ High current capability
- ✦ High reliability
- ✦ High surge current capability
- ✦ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application.

### Mechanical Data

- ✦ Case: Molded plastic DO-41
- ✦ Epoxy: UL 94V0 rate flame retardant
- ✦ Polarity: Color band denotes cathode
- ✦ High temperature soldering guaranteed:  
260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✦ Weight: 0.35 gram

### DO-41



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	HER 101G	HER 102G	HER 103G	HER 104G	HER 105G	HER 106G	HER 107G	HER 108G	Units	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_A = 55^\circ C$	$I_{(AV)}$	1.0								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	30								A	
Maximum Instantaneous Forward Voltage @ 1.0A	$V_F$	1.0			1.3		1.7			V	
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 125^\circ C$	$I_R$	5.0 150								$\mu A$ $\mu A$	
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$	50					75				nS
Typical Junction Capacitance ( Note 2 )	$C_j$	15					10				pF
Typical thermal resistance	$R_{\theta JA}$ $R_{\theta JC}$	70 15								$^\circ C/W$	
Operating Temperature Range	$T_J$	-65 to +150								$^\circ C$	
Storage Temperature Range	$T_{STG}$	-65 to +150								$^\circ C$	

- Notes:
1. Reverse Recovery Test Conditions:  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$
  2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
  3. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

### RATINGS AND CHARACTERISTIC CURVES (HER101G THRU HER108G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

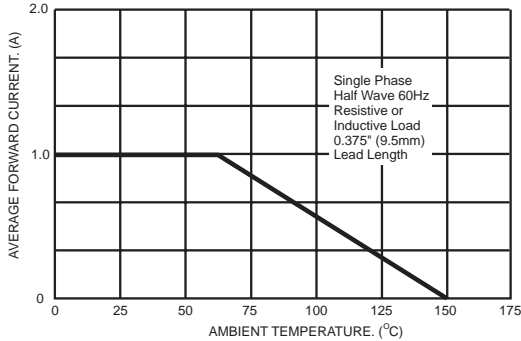


FIG.2- TYPICAL REVERSE CHARACTERISTICS

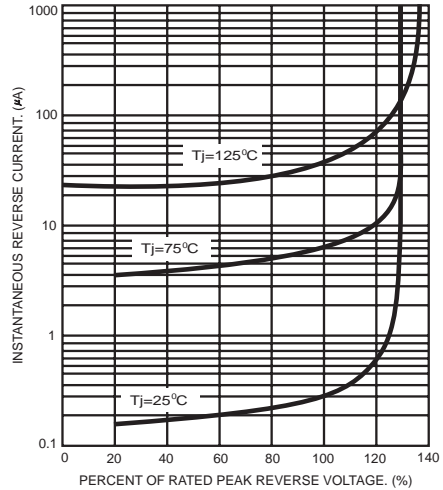


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

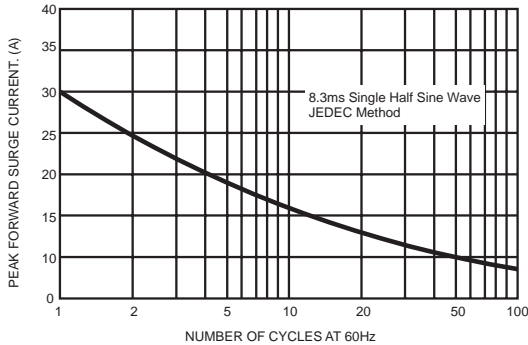


FIG.5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

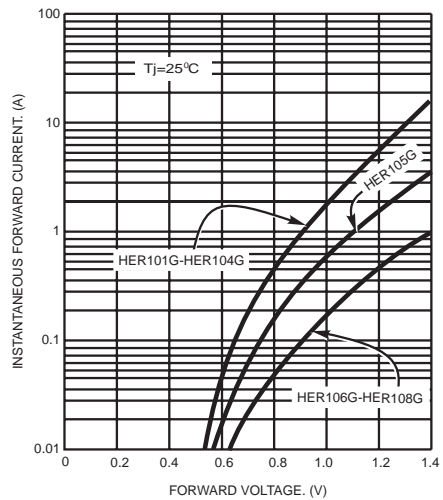


FIG.4- TYPICAL JUNCTION CAPACITANCE

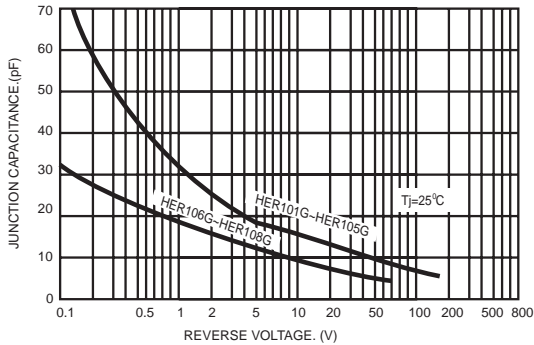


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

